


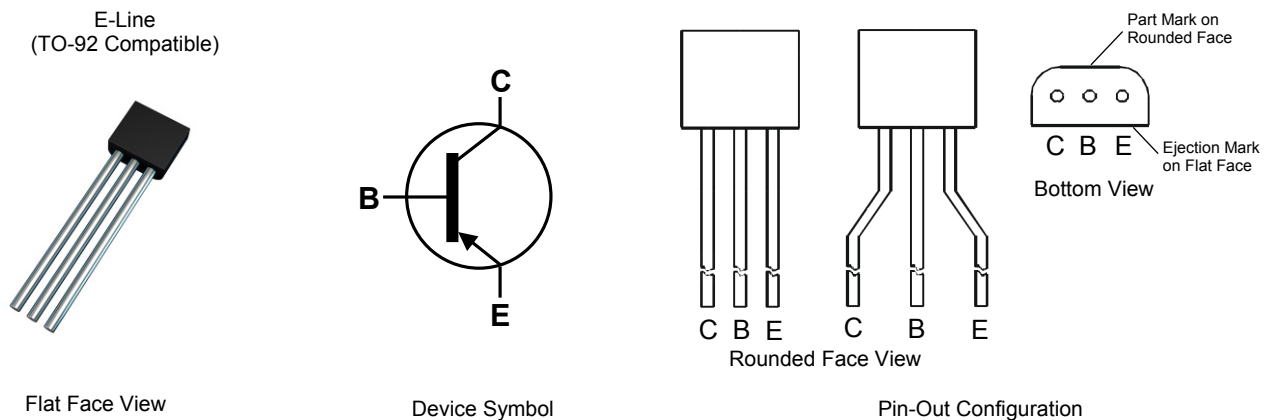
**200V PNP MEDIUM POWER HIGH GAIN TRANSISTOR IN E-LINE**

**Features**

- $BV_{CEO} > -200V$
- $I_C = -0.5A$  High Continuous Collector Current
- $I_{CM} = -1A$  Peak Pulse Current
- $T_J$  up to  $200^{\circ}C$  for High Temperature Operation
- $h_{FE} > 250 @ 0.3A$  for High Gain Hold-Up
- $P_D = 1W$  Power dissipation
- Complementary NPN Type: ZTX696B
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Mechanical Data**

- Case: E-Line (TO-92 Compatible)
- Case Material: molded plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 
- Weight: 0.159 grams (approximate)

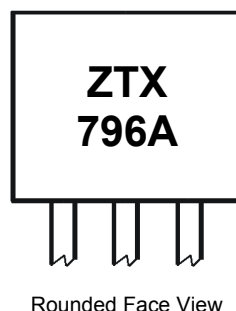


**Ordering Information (Note 4)**

Product	Marking	Package	Leads	Quantity
ZTX796ASTZ	ZTX796A	E-Line	Joggled	2,000 Taped per Ammo Box
ZTX796A	ZTX796A	E-Line	Straight	4,000 Loose in a Box

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**



ZTX796A = Product Type Marking Code

### Maximum Ratings (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

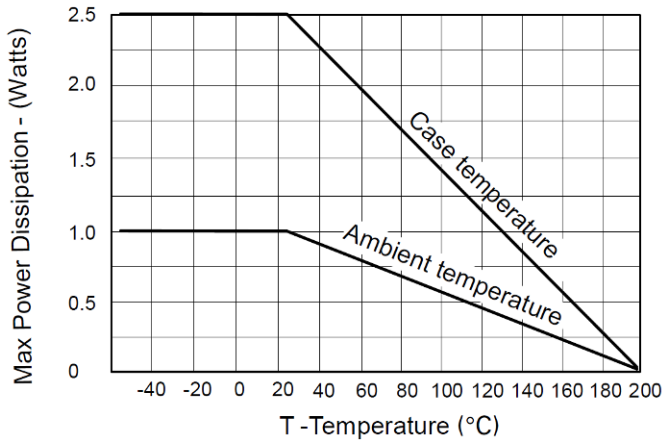
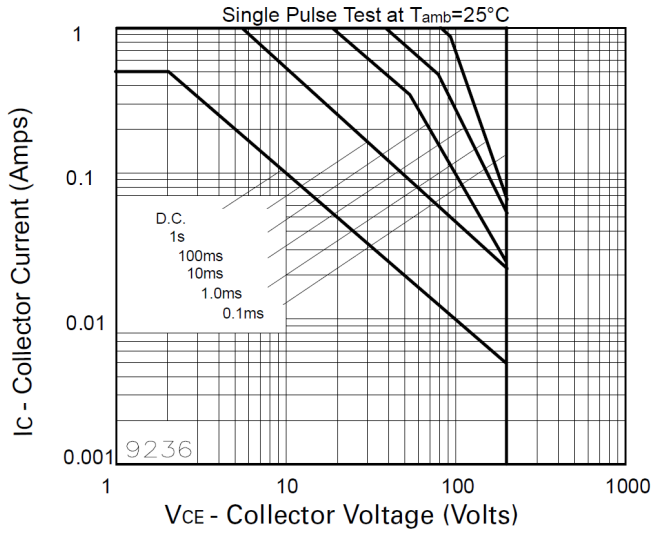
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-200	V
Collector-Emitter Voltage	$V_{CEO}$	-200	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Continuous Collector Current	$I_C$	-0.5	A
Peak Pulse Current	$I_{CM}$	-1	A

### Thermal Characteristics (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

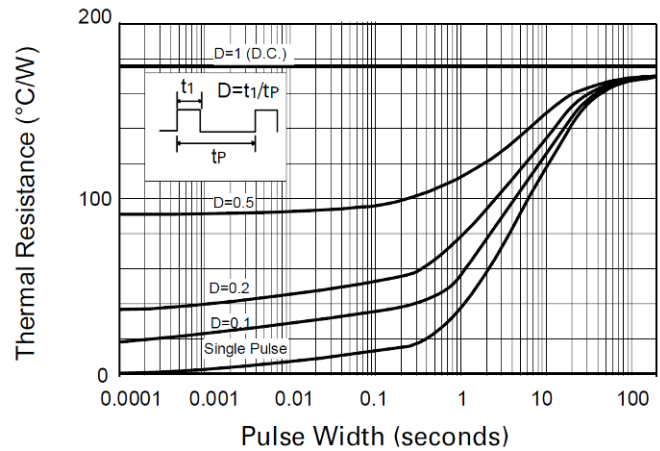
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	$P_D$	1.5	W
Power Dissipation (Note 6)	$P_D$	1	W
Thermal Resistance Junction to Ambient (Note 5)	$R_{\theta JA}$	116	$^\circ\text{C/W}$
Thermal Resistance Junction to Ambient (Note 6)	$R_{\theta JA}$	175	$^\circ\text{C/W}$
Thermal Resistance Junction to Lead (Note 7)	$R_{\theta JL}$	70	$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +200	$^\circ\text{C}$

- Notes:
5. For a through-hole device mounted at the seating plane (2.5mm lead length) with the collector lead on 25mm x 25mm 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  6. Same as note (5), except the device is mounted on minimum recommended pad layout with 12mm lead length from the bottom of package to the board.
  7. Thermal resistance from junction to solder-point at the seating plane (2.5mm from the bottom of package along the collector lead).

**Thermal Characteristics and Derating Information**



**Derating curve**



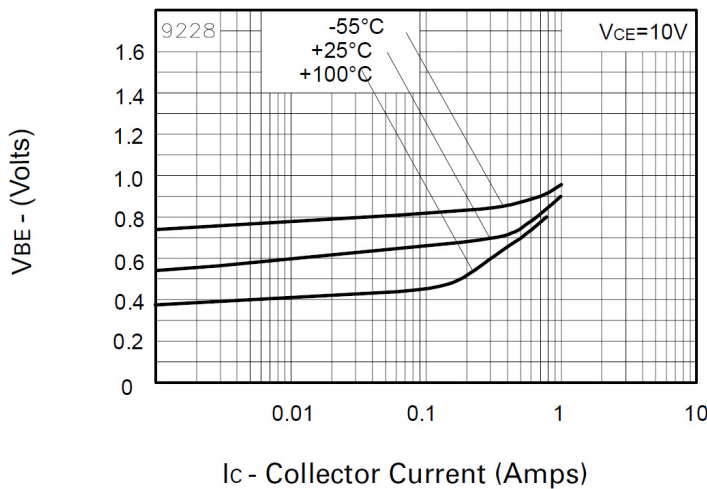
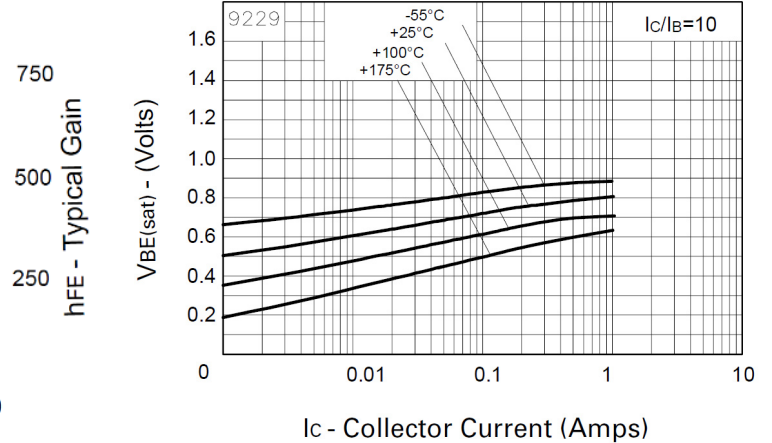
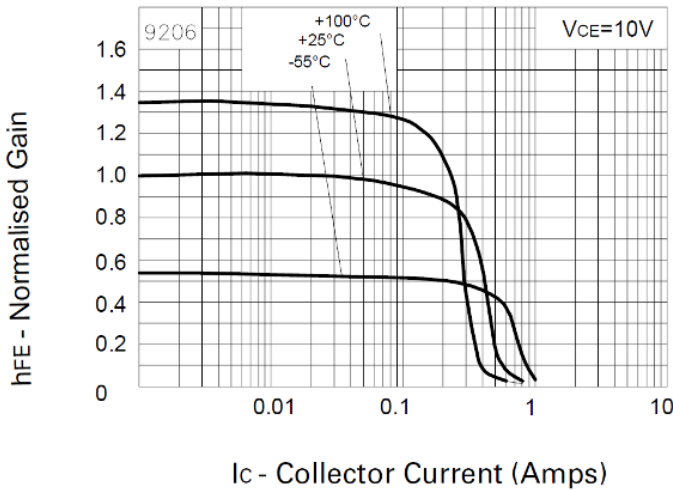
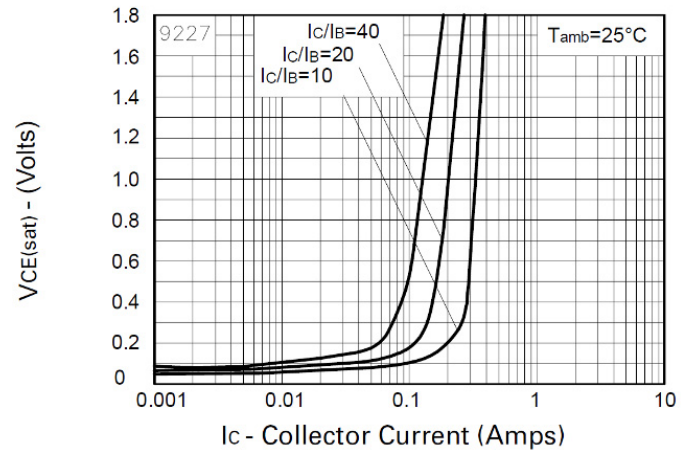
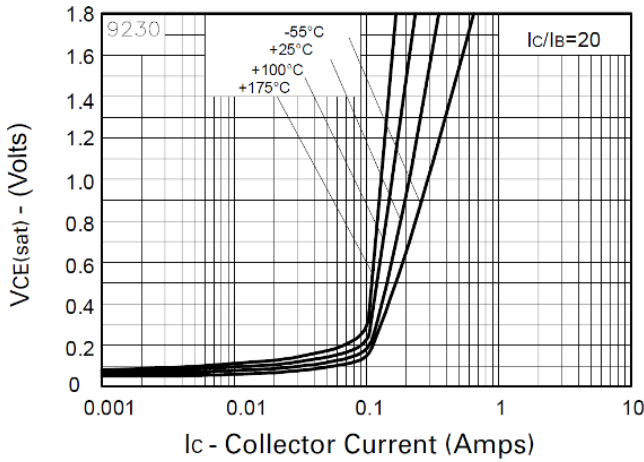
**Maximum transient thermal impedance**

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CB0</sub>	-200	—	—	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	-200	—	—	V	I <sub>C</sub> = -1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5	—	—	V	I <sub>E</sub> = -100μA
Collector-Emitter Cutoff Current	I <sub>CES</sub>	—	—	-0.1	μA	V <sub>CE</sub> = -150V
Collector-Base Cutoff Current	I <sub>CB0</sub>	—	—	-0.1	μA	V <sub>CB</sub> = -150V
Emitter-Base Cutoff Current	I <sub>EBO</sub>	—	—	-0.1	μA	V <sub>EB</sub> = -4V
Collector-Emitter Saturation Voltage (Note 7)	V <sub>CE(sat)</sub>	—	—	-0.2	mV	I <sub>C</sub> = -50mA, I <sub>B</sub> = -2mA
		—	—	-0.3	mV	I <sub>C</sub> = -100mA, I <sub>B</sub> = -5mA
		—	—	-0.3	mV	I <sub>C</sub> = -200mA, I <sub>B</sub> = -20mA
Base-Emitter Saturation Voltage (Note 7)	V <sub>BE(sat)</sub>	—	—	-0.95	mV	I <sub>C</sub> = -200mA, I <sub>B</sub> = -20mA
Base-Emitter Turn-On Voltage (Note 7)	V <sub>BE(on)</sub>	—	-0.67	—	mV	I <sub>C</sub> = -200mA, V <sub>CE</sub> = -10V
Static Forward Current Transfer Ratio (Note 7)	h <sub>FE</sub>	300	—	800	—	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -10V
		300	—	—	—	I <sub>C</sub> = -100mA, V <sub>CE</sub> = -10V
		250	—	—	—	I <sub>C</sub> = -300mA, V <sub>CE</sub> = -10V
		100	—	—	—	I <sub>C</sub> = -400mA, V <sub>CE</sub> = -10V
Transition Frequency	f <sub>T</sub>	100	—	—	MHz	V <sub>CE</sub> = -5V, I <sub>C</sub> = -50mA f = 50MHz
Input Capacitance	C <sub>ibo</sub>	—	225	—	pF	V <sub>EB</sub> = -0.5V, f = 1MHz
Output Capacitance	C <sub>obo</sub>	—	12	—	pF	V <sub>CB</sub> = -10V, f = 1MHz
Switching Times	t <sub>on</sub>	—	100	—	ns	V <sub>CC</sub> = -50V, I <sub>C</sub> = -100mA
	t <sub>off</sub>	—	3200	—	ns	I <sub>B1</sub> = -I <sub>B2</sub> = -10mA

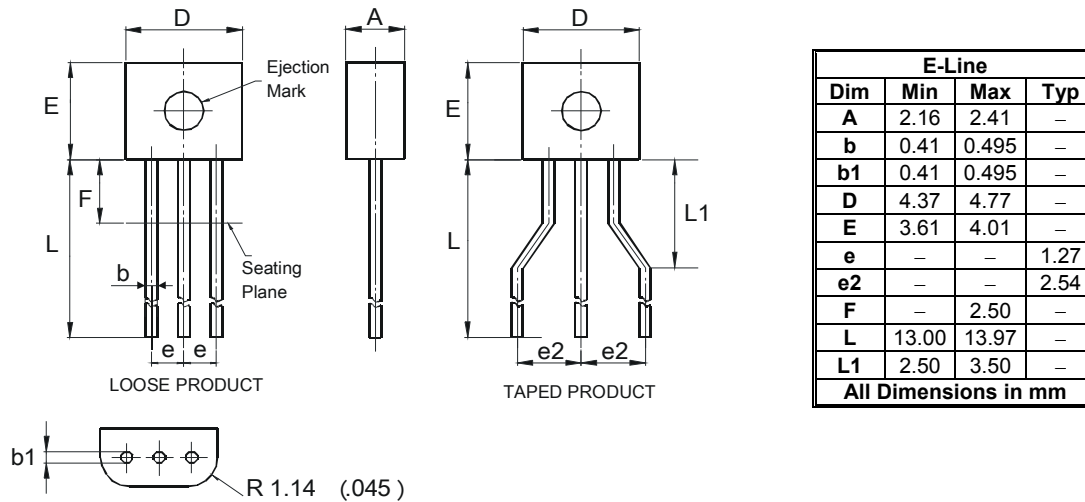
Note: 7. Measured under pulsed conditions. Pulse width ≤ 300 μs. Duty cycle ≤ 2%

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



## Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.

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### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

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